

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: 2751

Examiner: Kim, H.

Atty. Docket: 95-0653.01

Mailloux, et al.

Serial No.: 08/984,560

Filed: December 3, 1997

For: BURST/PIPELINED EDO MEMORY DEVICE

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INFORMATION DISCLOSURE STATEMENT

Group 2700

Assistant Commissioner for Patents Washington, D.C. 20231

references are not enclosed.

Dear Sir:

Certificate of Mailing (37 C.F.R.§ 1.8)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail, postage prepaid, in an

envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on the date below:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56, Applicant[s] respectfully request[s] that this Information Disclosure Statement be entered and that the references listed on the attached Form PTO-1449 be considered by the Examiner and made of record. As the references are cumulative from the parent, copies of the listed

In accordance with 37 C.F.R. § 1.97(b), this Information Disclosure Statement is not to be construed as a representation that a search has been made or that no other possible material information as defined in 37 C.F.R. § 1.56(a) exists.

The following references are submitted for the Examiner's review:

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Related Co-pending Applications

PCT Patent Application No. PCT/US95/16656, filed 12/21/1995, entitled: Burst Edo Memory Device

Address Counter.

PCT Patent Application No. PCT/US95/16984, filed 12/22/1995, entitled: Burst Edo Memory Device.

As this information is being submitted within three months of the date of filing of the application, Applicant understands that no fee or certification is required for the submission and consideration of this information at this time.

If there are any matters which may be resolved or clarified through telephone interview, the Examiner is respectfully requested to contact Applicant's undersigned attorney at the number indicated.

* * * *

A Form PTO-1449 is enclosed herewith.

Date: Z - ZZ-99

Respectfully submitted,

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